

# **Excellent Integrated System Limited**

Stocking Distributor

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ON Semiconductor MURHS160T3G

For any questions, you can email us directly: <u>sales@integrated-circuit.com</u>



Distributor of ON Semiconductor: Excellent Integrated System Limited Datasheet of MURHS160T3G - DIODE GEN PURP 600V 1A SMB Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

# MURHS160T3G, SURHS8160T3G

# **Power Rectifier**

## Features and Benefits

- Ultrafast 35 Nanosecond Recovery Times
- 175°C Operating Junction Temperature
- High Temperature Glass Passivated Junction
- High Voltage Capability to 600 V
- AEC-Q101 Qualified and PPAP Capable
- SURHS8 Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- This is a Pb-Free Device\*

## Applications

- Power Supplies
- Inverters
- Free Wheeling Diodes

## **Mechanical Characteristics**

- Case: Epoxy, Molded
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Weight: 95 mg (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- · Cathode Polarity Band

## MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	600	V
Average Rectified Forward Current (Rated $V_R$ , $T_L$ = 145°C)	I <sub>F(AV)</sub>	1.0	A
Nonrepetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I <sub>FSM</sub>	15	A
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	–65 to +175	°C
ESD Ratings: Machine Model = C Human Body Model = 3B		> 400 > 8000	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



# **ON Semiconductor®**

http://onsemi.com

# **ULTRAFAST RECTIFIER 1.0 AMPERES 600 VOLTS**

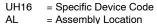


SMR CASE 403A PLASTIC

10 -02

## MARKING DIAGRAM





= Assembly Location

= Year

Y

- WW = Work Week
  - = Pb-Free Package

(Note: Microdot may be in either location)

### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MURHS160T3G	SMB (Pb-Free)	2,500 / Tape & Reel
SURHS8160T3G	SMB (Pb-Free)	2,500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.



# MURHS160T3G, SURHS8160T3G

## THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Maximum Thermal Resistance, Junction-to-Lead (Note 1)	$R_{ heta JL}$	24	°C/W
Maximum Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\thetaJA}$	80	°C/W

Mounted with minimum recommended pad size, PC Board FR4.
1 inch square pad size (1 x 0.5 inch for each lead) on FR4 board.

## **ELECTRICAL CHARACTERISTICS**

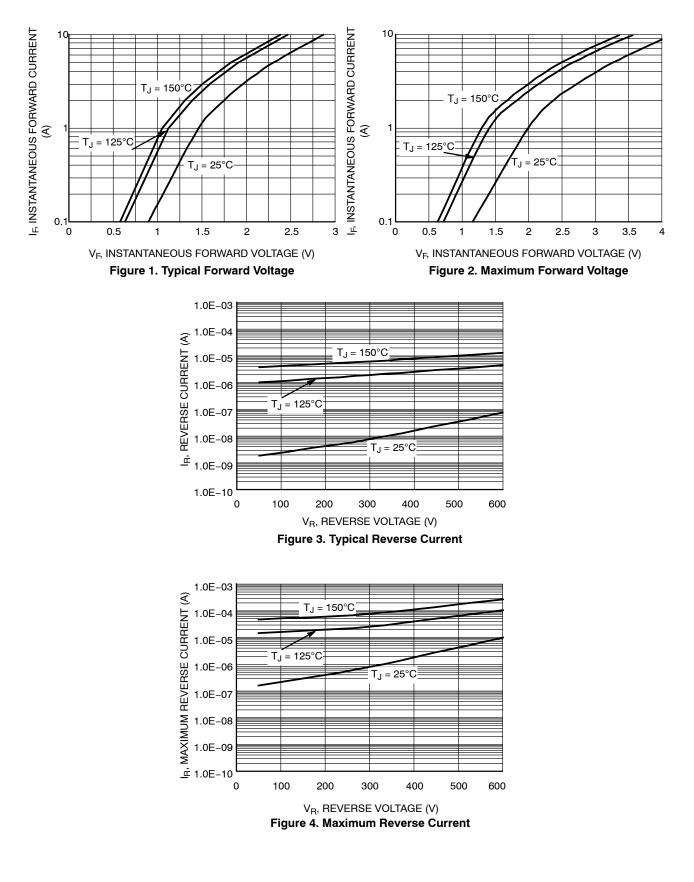
Rating	Symbol	Тур	Max	Unit	
Maximum Instantaneous Forward Voltage (Note 3) (I <sub>F</sub> = 1.0 A, T <sub>C</sub> = 25°C) (I <sub>F</sub> = 1.0 A, T <sub>C</sub> = 125°C)	V <sub>F</sub>	1.5 1.2	2.4 1.7	V	
Maximum Instantaneous Reverse Current (Note 3) (Rated dc Voltage, $T_C = 25^{\circ}C$ ) (Rated dc Voltage, $T_C = 125^{\circ}C$ )	I <sub>R</sub>	0.18 5.0	20 200	μΑ	
	t <sub>rr</sub>	25 16	35 30	ns	

3. Pulse Test: Pulse Width = 300  $\mu$ s, Duty Cycle  $\leq$  2.0%.



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# MURHS160T3G, SURHS8160T3G

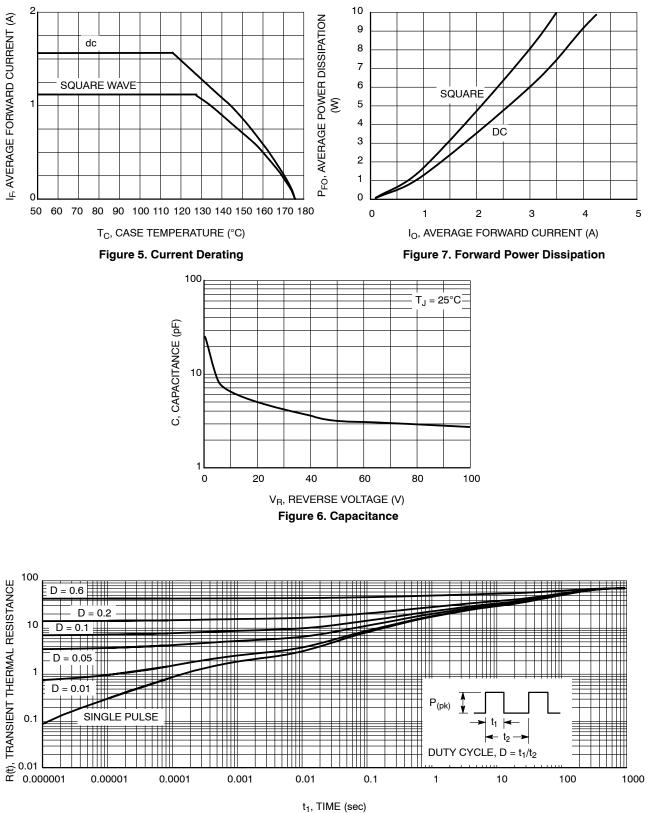
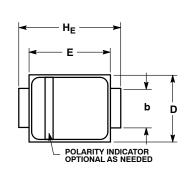


Figure 8. Thermal Response Junction-to-Ambient



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## PACKAGE DIMENSIONS

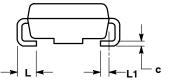


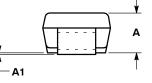
SMB CASE 403A-03 **ISSUE H** 

> NOTES DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH. D DIMENSION SHALL BE MEASURED WITHIN DIMENSION P. 2.

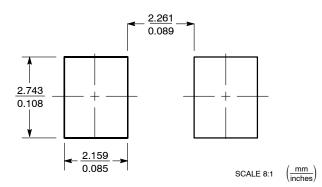
3.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.90	2.20	2.28	0.075	0.087	0.090
A1	0.05	0.10	0.19	0.002	0.004	0.007
b	1.96	2.03	2.20	0.077	0.080	0.087
с	0.15	0.23	0.31	0.006	0.009	0.012
D	3.30	3.56	3.95	0.130	0.140	0.156
E	4.06	4.32	4.60	0.160	0.170	0.181
HE	5.21	5.44	5.60	0.205	0.214	0.220
L	0.76	1.02	1.60	0.030	0.040	0.063
L1	0.51 REF			0.020 REF		





SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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MURHS160/D